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Applications of "[Embedded - Microcontrollers](#)"

Details

| | |
|----------------------------|---|
| Product Status | Not For New Designs |
| Core Processor | R8C |
| Core Size | 16-Bit |
| Speed | 20MHz |
| Connectivity | I ² C, LINbus, SIO, SSU, UART/USART |
| Peripherals | POR, Voltage Detect, WDT |
| Number of I/O | 41 |
| Program Memory Size | 16KB (16K x 8) |
| Program Memory Type | FLASH |
| EEPROM Size | - |
| RAM Size | 1K x 8 |
| Voltage - Supply (Vcc/Vdd) | 2.2V ~ 5.5V |
| Data Converters | A/D 12x10b |
| Oscillator Type | Internal |
| Operating Temperature | -40°C ~ 85°C (TA) |
| Mounting Type | Surface Mount |
| Package / Case | 52-LQFP |
| Supplier Device Package | 52-LQFP (10x10) |
| Purchase URL | https://www.e-xfl.com/product-detail/renesas-electronics-america/r5f21244sdfp-x6 |

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Table 1.4 Product Information for R8C/25 Group

Current of Feb. 2008

| Type No. | ROM Capacity | | RAM Capacity | Package Type | Remarks |
|-----------------|--------------|-------------|--------------|--------------|---|
| | Program ROM | Data flash | | | |
| R5F21254SNFP | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PLQP0052JA-A | N version Blank product |
| R5F21255SNFP | 24 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21256SNFP | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21257SNFP | 48 Kbytes | 1 Kbyte × 2 | 2.5 Kbytes | PLQP0052JA-A | |
| R5F21258SNFP | 64 Kbytes | 1 Kbyte × 2 | 3 Kbytes | PLQP0052JA-A | |
| R5F21254SNLG | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PTLG0064JA-A | |
| R5F21256SNLG | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PTLG0064JA-A | D version Blank product |
| R5F21254SDFP | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PLQP0052JA-A | |
| R5F21255SDFP | 24 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21256SDFP | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21257SDFP | 48 Kbytes | 1 Kbyte × 2 | 2.5 Kbytes | PLQP0052JA-A | |
| R5F21258SDFP | 64 Kbytes | 1 Kbyte × 2 | 3 Kbytes | PLQP0052JA-A | |
| R5F21254SNXXXFP | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PLQP0052JA-A | N version Factory programming product ⁽¹⁾ |
| R5F21255SNXXXFP | 24 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21256SNXXXFP | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21257SNXXXFP | 48 Kbytes | 1 Kbyte × 2 | 2.5 Kbytes | PLQP0052JA-A | |
| R5F21258SNXXXFP | 64 Kbytes | 1 Kbyte × 2 | 3 Kbytes | PLQP0052JA-A | |
| R5F21254SNXXXLG | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PTLG0064JA-A | |
| R5F21256SNXXXLG | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PTLG0064JA-A | D version Factory programming product ⁽¹⁾ |
| R5F21254SDXXXFP | 16 Kbytes | 1 Kbyte × 2 | 1 Kbyte | PLQP0052JA-A | |
| R5F21255SDXXXFP | 24 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21256SDXXXFP | 32 Kbytes | 1 Kbyte × 2 | 2 Kbytes | PLQP0052JA-A | |
| R5F21257SDXXXFP | 48 Kbytes | 1 Kbyte × 2 | 2.5 Kbytes | PLQP0052JA-A | |
| R5F21258SDXXXFP | 64 Kbytes | 1 Kbyte × 2 | 3 Kbytes | PLQP0052JA-A | |

NOTE:

1. The user ROM is programmed before shipment.

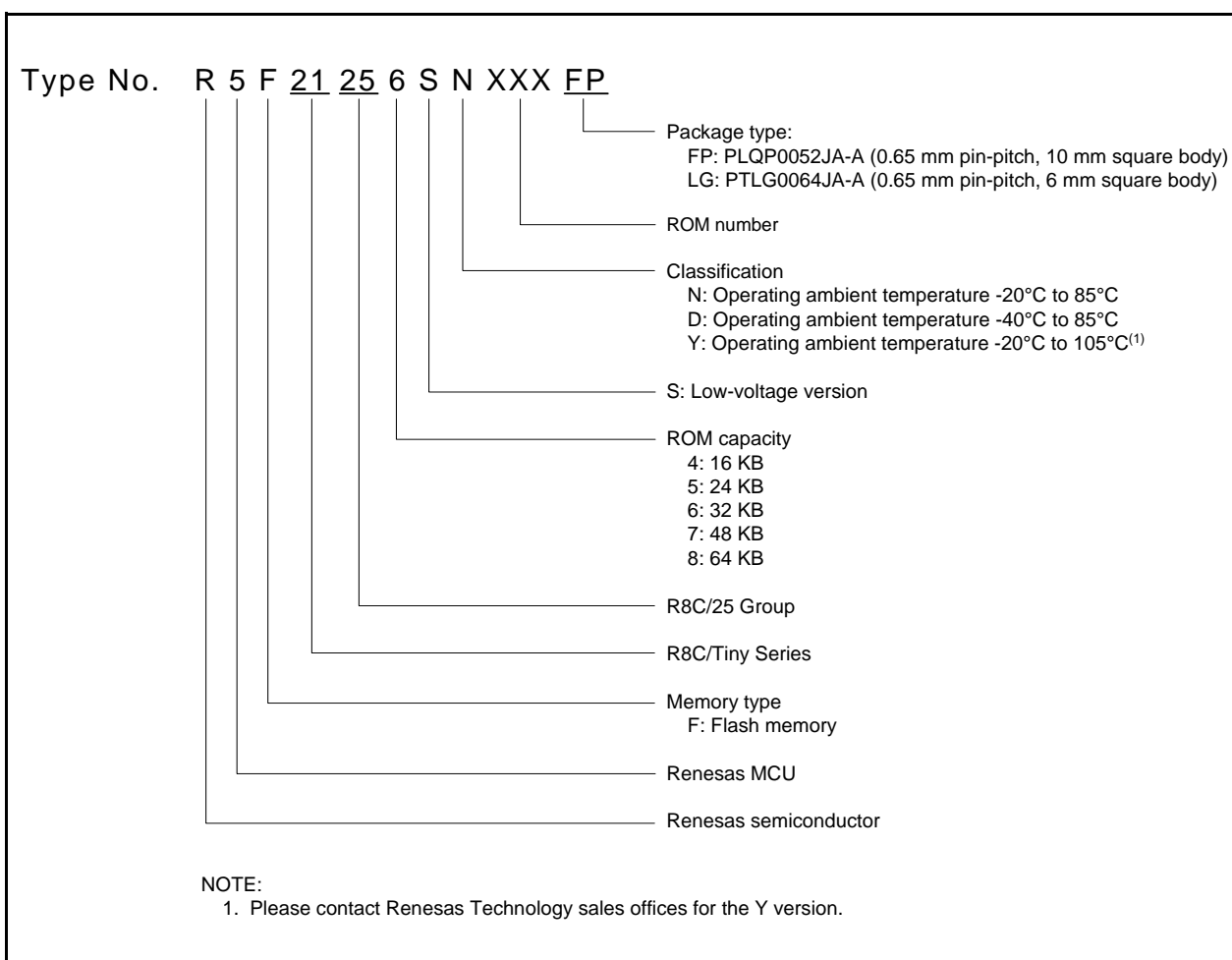


Figure 1.3 Type Number, Memory Size, and Package of R8C/25 Group

2. Central Processing Unit (CPU)

Figure 2.1 shows the CPU Registers. The CPU contains 13 registers. R0, R1, R2, R3, A0, A1, and FB configure a register bank. There are two sets of register bank.

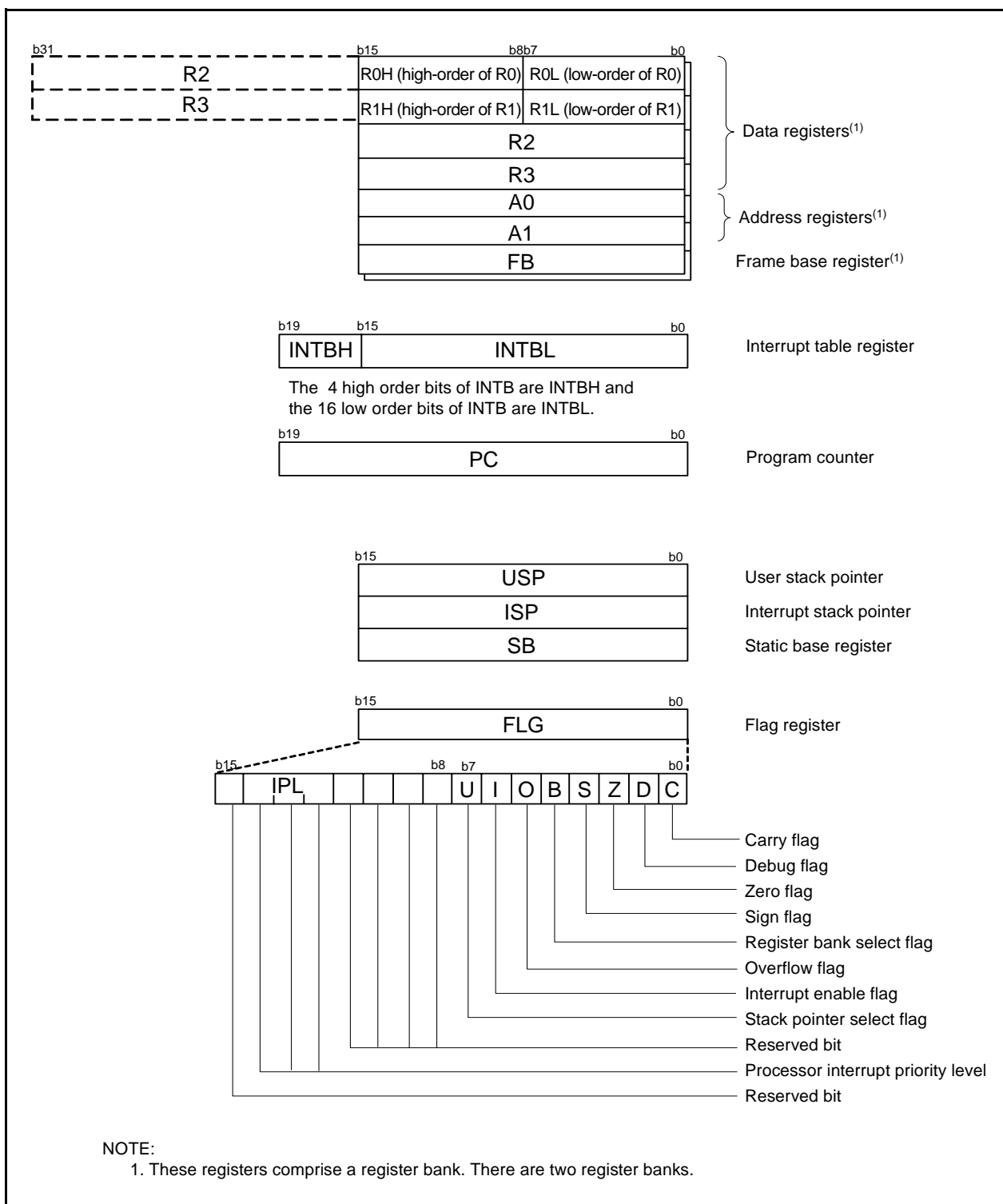


Figure 2.1 CPU Registers

2.8.7 Interrupt Enable Flag (I)

The I flag enables maskable interrupts.

Interrupt are disabled when the I flag is set to 0, and are enabled when the I flag is set to 1. The I flag is set to 0 when an interrupt request is acknowledged.

2.8.8 Stack Pointer Select Flag (U)

ISP is selected when the U flag is set to 0; USP is selected when the U flag is set to 1.

The U flag is set to 0 when a hardware interrupt request is acknowledged or the INT instruction of software interrupt numbers 0 to 31 is executed.

2.8.9 Processor Interrupt Priority Level (IPL)

IPL is 3 bits wide and assigns processor interrupt priority levels from level 0 to level 7.

If a requested interrupt has higher priority than IPL, the interrupt is enabled.

2.8.10 Reserved Bit

If necessary, set to 0. When read, the content is undefined.

Table 4.3 SFR Information (3)⁽¹⁾

| Address | Register | Symbol | After reset |
|---------|---|---------------|-----------------|
| 0080h | | | |
| 0081h | | | |
| 0082h | | | |
| 0083h | | | |
| 0084h | | | |
| 0085h | | | |
| 0086h | | | |
| 0087h | | | |
| 0088h | | | |
| 0089h | | | |
| 008Ah | | | |
| 008Bh | | | |
| 008Ch | | | |
| 008Dh | | | |
| 008Eh | | | |
| 008Fh | | | |
| 0090h | | | |
| 0091h | | | |
| 0092h | | | |
| 0093h | | | |
| 0094h | | | |
| 0095h | | | |
| 0096h | | | |
| 0097h | | | |
| 0098h | | | |
| 0099h | | | |
| 009Ah | | | |
| 009Bh | | | |
| 009Ch | | | |
| 009Dh | | | |
| 009Eh | | | |
| 009Fh | | | |
| 00A0h | UART0 Transmit/Receive Mode Register | U0MR | 00h |
| 00A1h | UART0 Bit Rate Register | U0BRG | XXh |
| 00A2h | UART0 Transmit Buffer Register | U0TB | XXh |
| 00A3h | | | XXh |
| 00A4h | UART0 Transmit/Receive Control Register 0 | U0C0 | 00001000b |
| 00A5h | UART0 Transmit/Receive Control Register 1 | U0C1 | 00000010b |
| 00A6h | UART0 Receive Buffer Register | U0RB | XXh |
| 00A7h | | | XXh |
| 00A8h | UART1 Transmit/Receive Mode Register | U1MR | 00h |
| 00A9h | UART1 Bit Rate Register | U1BRG | XXh |
| 00AAh | UART1 Transmit Buffer Register | U1TB | XXh |
| 00ABh | | | XXh |
| 00ACh | UART1 Transmit/Receive Control Register 0 | U1C0 | 00001000b |
| 00ADh | UART1 Transmit/Receive Control Register 1 | U1C1 | 00000010b |
| 00AEh | UART1 Receive Buffer Register | U1RB | XXh |
| 00AFh | | | XXh |
| 00B0h | | | |
| 00B1h | | | |
| 00B2h | | | |
| 00B3h | | | |
| 00B4h | | | |
| 00B5h | | | |
| 00B6h | | | |
| 00B7h | | | |
| 00B8h | SS Control Register H / IIC bus Control Register 1 ⁽²⁾ | SSCRH / ICCR1 | 00h |
| 00B9h | SS Control Register L / IIC bus Control Register 2 ⁽²⁾ | SSCRL / ICCR2 | 01111101b |
| 00BAh | SS Mode Register / IIC bus Mode Register ⁽²⁾ | SSMR / ICMR | 00011000b |
| 00BBh | SS Enable Register / IIC bus Interrupt Enable Register ⁽²⁾ | SSER / ICIER | 00h |
| 00BCh | SS Status Register / IIC bus Status Register ⁽²⁾ | SSSR / ICSR | 00h / 0000X000b |
| 00BDh | SS Mode Register 2 / Slave Address Register ⁽²⁾ | SSMR2 / SAR | 00h |
| 00BEh | SS Transmit Data Register / IIC bus Transmit Data Register ⁽²⁾ | SSTDR / ICDRT | FFh |
| 00BFh | SS Receive Data Register / IIC bus Receive Data Register ⁽²⁾ | SSRDR / ICDRR | FFh |

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. Selected by the IICSEL bit in the PMR register.

Table 4.6 SFR Information (6)⁽¹⁾

| Address | Register | Symbol | After reset |
|---------|---|----------|-------------|
| 0140h | Timer RD Control Register 0 | TRDCR0 | 00h |
| 0141h | Timer RD I/O Control Register A0 | TRDIOA0 | 10001000b |
| 0142h | Timer RD I/O Control Register C0 | TRDIORC0 | 10001000b |
| 0143h | Timer RD Status Register 0 | TRDSR0 | 11100000b |
| 0144h | Timer RD Interrupt Enable Register 0 | TRDIER0 | 11100000b |
| 0145h | Timer RD PWM Mode Output Level Control Register 0 | TRDPOCR0 | 11111000b |
| 0146h | Timer RD Counter 0 | TRD0 | 00h |
| 0147h | | | 00h |
| 0148h | Timer RD General Register A0 | TRDGRA0 | FFh |
| 0149h | | | FFh |
| 014Ah | Timer RD General Register B0 | TRDGRB0 | FFh |
| 014Bh | | | FFh |
| 014Ch | Timer RD General Register C0 | TRDGRC0 | FFh |
| 014Dh | | | FFh |
| 014Eh | Timer RD General Register D0 | TRDGRD0 | FFh |
| 014Fh | | | FFh |
| 0150h | Timer RD Control Register 1 | TRDCR1 | 00h |
| 0151h | Timer RD I/O Control Register A1 | TRDIOA1 | 10001000b |
| 0152h | Timer RD I/O Control Register C1 | TRDIORC1 | 10001000b |
| 0153h | Timer RD Status Register 1 | TRDSR1 | 11000000b |
| 0154h | Timer RD Interrupt Enable Register 1 | TRDIER1 | 11100000b |
| 0155h | Timer RD PWM Mode Output Level Control Register 1 | TRDPOCR1 | 11111000b |
| 0156h | Timer RD Counter 1 | TRD1 | 00h |
| 0157h | | | 00h |
| 0158h | Timer RD General Register A1 | TRDGRA1 | FFh |
| 0159h | | | FFh |
| 015Ah | Timer RD General Register B1 | TRDGRB1 | FFh |
| 015Bh | | | FFh |
| 015Ch | Timer RD General Register C1 | TRDGRC1 | FFh |
| 015Dh | | | FFh |
| 015Eh | Timer RD General Register D1 | TRDGRD1 | FFh |
| 015Fh | | | FFh |
| 0160h | | | |
| 0161h | | | |
| 0162h | | | |
| 0163h | | | |
| 0164h | | | |
| 0165h | | | |
| 0166h | | | |
| 0167h | | | |
| 0168h | | | |
| 0169h | | | |
| 016Ah | | | |
| 016Bh | | | |
| 016Ch | | | |
| 016Dh | | | |
| 016Eh | | | |
| 016Fh | | | |
| 0170h | | | |
| 0171h | | | |
| 0172h | | | |
| 0173h | | | |
| 0174h | | | |
| 0175h | | | |
| 0176h | | | |
| 0177h | | | |
| 0178h | | | |
| 0179h | | | |
| 017Ah | | | |
| 017Bh | | | |
| 017Ch | | | |
| 017Dh | | | |
| 017Eh | | | |
| 017Fh | | | |

X: Undefined

NOTE:

1. The blank regions are reserved. Do not access locations in these regions.

Table 4.7 SFR Information (7)⁽¹⁾

| Address | Register | Symbol | After reset |
|---------|---------------------------------|--------|-------------|
| 0180h | | | |
| 0181h | | | |
| 0182h | | | |
| 0183h | | | |
| 0184h | | | |
| 0185h | | | |
| 0186h | | | |
| 0187h | | | |
| 0188h | | | |
| 0189h | | | |
| 018Ah | | | |
| 018Bh | | | |
| 018Ch | | | |
| 018Dh | | | |
| 018Eh | | | |
| 018Fh | | | |
| 0190h | | | |
| 0191h | | | |
| 0192h | | | |
| 0193h | | | |
| 0194h | | | |
| 0195h | | | |
| 0196h | | | |
| 0197h | | | |
| 0198h | | | |
| 0199h | | | |
| 019Ah | | | |
| 019Bh | | | |
| 019Ch | | | |
| 019Dh | | | |
| 019Eh | | | |
| 019Fh | | | |
| 01A0h | | | |
| 01A1h | | | |
| 01A2h | | | |
| 01A3h | | | |
| 01A4h | | | |
| 01A5h | | | |
| 01A6h | | | |
| 01A7h | | | |
| 01A8h | | | |
| 01A9h | | | |
| 01AAh | | | |
| 01ABh | | | |
| 01ACh | | | |
| 01ADh | | | |
| 01AEh | | | |
| 01AFh | | | |
| 01B0h | | | |
| 01B1h | | | |
| 01B2h | | | |
| 01B3h | Flash Memory Control Register 4 | FMR4 | 01000000b |
| 01B4h | | | |
| 01B5h | Flash Memory Control Register 1 | FMR1 | 1000000Xb |
| 01B6h | | | |
| 01B7h | Flash Memory Control Register 0 | FMR0 | 00000001b |
| 01B8h | | | |
| 01B9h | | | |
| 01BAh | | | |
| 01BBh | | | |
| 01BCh | | | |
| 01BDh | | | |
| 01BEh | | | |
| 01BFh | | | |
| FFFFh | Option Function Select Register | OFS | (Note 2) |

X: Undefined

NOTES:

1. The blank regions are reserved. Do not access locations in these regions.
2. The OFS register cannot be changed by a program. Use a flash programmer to write to it.

Table 5.2 Recommended Operating Conditions

| Symbol | Parameter | | Conditions | Standard | | | Unit |
|-----------------------------------|--|---|--|---------------------|------|---------------------|------|
| | | | | Min. | Typ. | Max. | |
| V _{CC} /AV _{CC} | Supply voltage | | | 2.2 | — | 5.5 | V |
| V _{SS} /AV _{SS} | Supply voltage | | | — | 0 | — | V |
| V _{IH} | Input "H" voltage | | | 0.8 V _{CC} | — | V _{CC} | V |
| V _{IL} | Input "L" voltage | | | 0 | — | 0.2 V _{CC} | V |
| I _{OH} (sum) | Peak sum output "H" current | Sum of all pins I _{OH} (peak) | | — | — | -160 | mA |
| I _{OH} (sum) | Average sum output "H" current | Sum of all pins I _{OH} (avg) | | — | — | -80 | mA |
| I _{OH} (peak) | Peak output "H" current | Except P2_0 to P2_7 | | — | — | -10 | mA |
| | | P2_0 to P2_7 | | — | — | -40 | mA |
| I _{OH} (avg) | Average output "H" current | Except P2_0 to P2_7 | | — | — | -5 | mA |
| | | P2_0 to P2_7 | | — | — | -20 | mA |
| I _{OL} (sum) | Peak sum output "L" current | Sum of all pins I _{OL} (peak) | | — | — | 160 | mA |
| I _{OL} (sum) | Average sum output "L" current | Sum of all pins I _{OL} (avg) | | — | — | 80 | mA |
| I _{OL} (peak) | Peak output "L" current | Except P2_0 to P2_7 | | — | — | 10 | mA |
| | | P2_0 to P2_7 | | — | — | 40 | mA |
| I _{OL} (avg) | Average output "L" current | Except P2_0 to P2_7 | | — | — | 5 | mA |
| | | P2_0 to P2_7 | | — | — | 20 | mA |
| f(XIN) | XIN clock input oscillation frequency | | 3.0 V ≤ V _{CC} ≤ 5.5 V | 0 | — | 20 | MHz |
| | | | 2.7 V ≤ V _{CC} < 3.0 V | 0 | — | 10 | MHz |
| | | | 2.2 V ≤ V _{CC} < 2.7 V | 0 | — | 5 | MHz |
| f(XCIN) | XCIN clock input oscillation frequency | | 2.2 V ≤ V _{CC} ≤ 5.5 V | 0 | — | 70 | kHz |
| — | System clock | OCD2 = 0 XIN clock selected | 3.0 V ≤ V _{CC} ≤ 5.5 V | 0 | — | 20 | MHz |
| | | | 2.7 V ≤ V _{CC} < 3.0 V | 0 | — | 10 | MHz |
| | | | 2.2 V ≤ V _{CC} < 2.7 V | 0 | — | 5 | MHz |
| | | OCD2 = 1 On-chip oscillator clock selected | FRA01 = 0 Low-speed on-chip oscillator clock selected | — | 125 | — | kHz |
| | | | FRA01 = 1 High-speed on-chip oscillator clock selected 3.0 V ≤ V _{CC} ≤ 5.5 V | — | — | 20 | MHz |
| | | | FRA01 = 1 High-speed on-chip oscillator clock selected 2.7 V ≤ V _{CC} ≤ 5.5 V | — | — | 10 | MHz |
| | | | FRA01 = 1 High-speed on-chip oscillator clock selected 2.2 V ≤ V _{CC} ≤ 5.5 V | — | — | 5 | MHz |

NOTES:

1. V_{CC} = 2.2 to 5.5 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. The average output current indicates the average value of current measured during 100 ms.

Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical Characteristics⁽⁴⁾

| Symbol | Parameter | Conditions | Standard | | | Unit |
|-------------------------|---|-----------------------------|-----------------------|------|----------------------------|-------|
| | | | Min. | Typ. | Max. | |
| — | Program/erase endurance ⁽²⁾ | | 10,000 ⁽³⁾ | — | — | times |
| — | Byte program time (program/erase endurance ≤ 1,000 times) | | — | 50 | 400 | μs |
| — | Byte program time (program/erase endurance > 1,000 times) | | — | 65 | — | μs |
| — | Block erase time (program/erase endurance ≤ 1,000 times) | | — | 0.2 | 9 | s |
| — | Block erase time (program/erase endurance > 1,000 times) | | — | 0.3 | — | s |
| t _d (SR-SUS) | Time delay from suspend request until suspend | | — | — | 97+CPU clock × 6 cycles | μs |
| — | Interval from erase start/restart until following suspend request | | 650 | — | — | μs |
| — | Interval from program start/restart until following suspend request | | 0 | — | — | ns |
| — | Time from suspend until program/erase restart | | — | — | 3+CPU clock × 4 cycles | μs |
| — | Program, erase voltage | | 2.7 | — | 5.5 | V |
| — | Read voltage | | 2.2 | — | 5.5 | V |
| — | Program, erase temperature | | -20 ⁽⁸⁾ | — | 85 | °C |
| — | Data hold time ⁽⁹⁾ | Ambient temperature = 55 °C | 20 | — | — | year |

NOTES:

1. V_{CC} = 2.7 to 5.5 V at T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. Definition of programming/erasure endurance
The programming and erasure endurance is defined on a per-block basis.
If the programming and erasure endurance is n (n = 100 or 10,000), each block can be erased n times. For example, if 1,024 1-byte writes are performed to block A, a 1 Kbyte block, and then the block is erased, the programming/erasure endurance still stands at one.
However, the same address must not be programmed more than once per erase operation (overwriting prohibited).
3. Endurance to guarantee all electrical characteristics after program and erase. (1 to Min. value can be guaranteed).
4. Standard of block A and block B when program and erase endurance exceeds 1,000 times. Byte program time to 1,000 times is the same as that in program ROM.
5. In a system that executes multiple programming operations, the actual erasure count can be reduced by writing to sequential addresses in turn so that as much of the block as possible is used up before performing an erase operation. For example, when programming groups of 16 bytes, the effective number of rewrites can be minimized by programming up to 128 groups before erasing them all in one operation. It is also advisable to retain data on the erase count of each block and limit the number of erase operations to a certain number.
6. If an error occurs during block erase, attempt to execute the clear status register command, then execute the block erase command at least three times until the erase error does not occur.
7. Customers desiring program/erase failure rate information should contact their Renesas technical support representative.
8. -40°C for D version.
9. The data hold time includes time that the power supply is off or the clock is not supplied.

Table 5.9 Power-on Reset Circuit, Voltage Monitor 0 Reset Electrical Characteristics⁽³⁾

| Symbol | Parameter | Condition | Standard | | | Unit |
|-------------------|---|-----------|----------|------|-------------------|---------|
| | | | Min. | Typ. | Max. | |
| V _{por1} | Power-on reset valid voltage ⁽⁴⁾ | | – | – | 0.1 | V |
| V _{por2} | Power-on reset or voltage monitor 0 reset valid voltage | | 0 | – | V _{det0} | V |
| t _{rth} | External power V _{CC} rise gradient ⁽²⁾ | | 20 | – | – | mV/msec |

NOTES:

1. The measurement condition is T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. This condition (external power V_{CC} rise gradient) does not apply if V_{CC} ≥ 1.0 V.
3. To use the power-on reset function, enable voltage monitor 0 reset by setting the LVD0ON bit in the OFS register to 0, the VW0C0 and VW0C6 bits in the VW0C register to 1 respectively, and the VCA25 bit in the VCA2 register to 1.
4. t_{w(por1)} indicates the duration the external power V_{CC} must be held below the effective voltage (V_{por1}) to enable a power on reset. When turning on the power for the first time, maintain t_{w(por1)} for 30 s or more if -20°C ≤ T_{opr} ≤ 85°C, maintain t_{w(por1)} for 3,000 s or more if -40°C ≤ T_{opr} < -20°C.

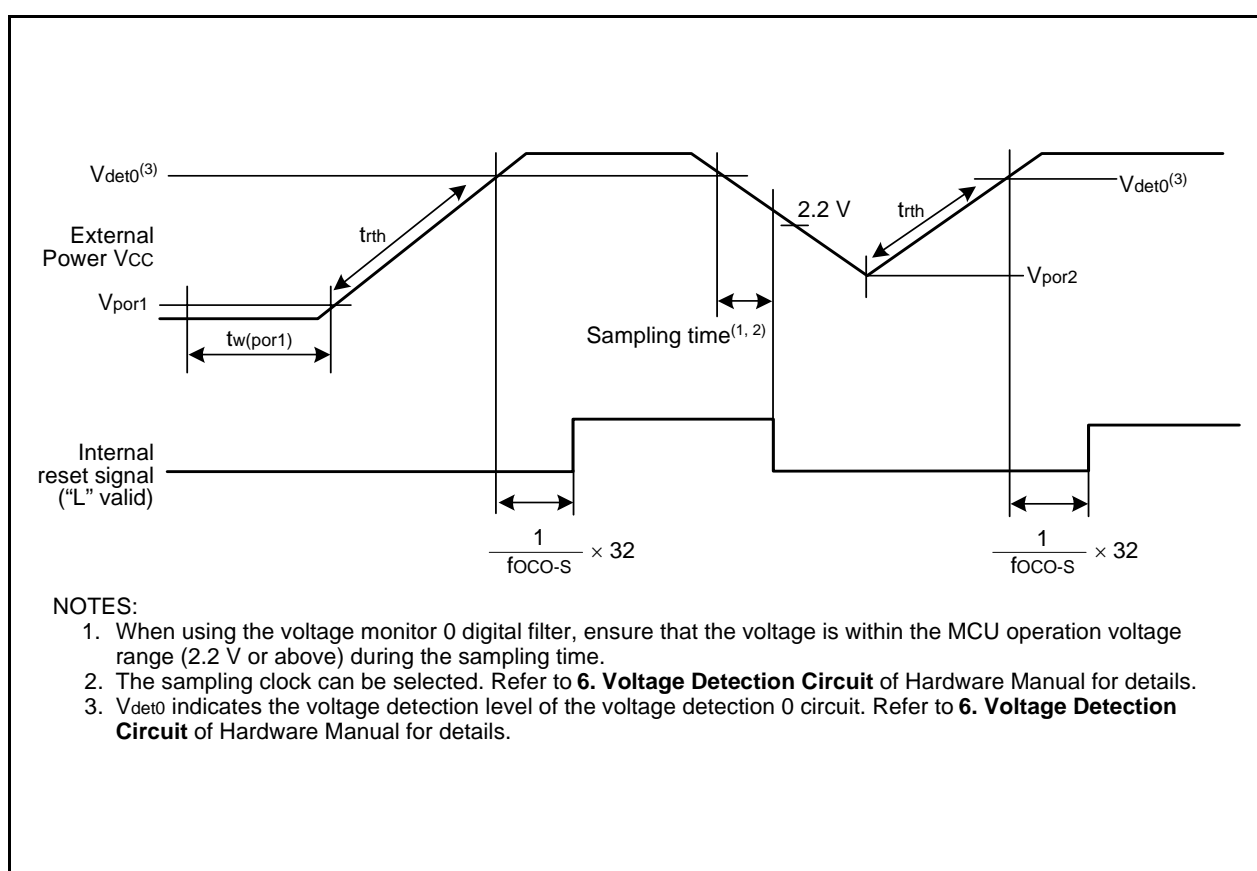
**Figure 5.3 Power-on Reset Circuit Electrical Characteristics**

Table 5.10 High-speed On-Chip Oscillator Circuit Electrical Characteristics

| Symbol | Parameter | Condition | Standard | | | Unit |
|---------|---|--|----------|--------|------|------|
| | | | Min. | Typ. | Max. | |
| fOCO40M | High-speed on-chip oscillator frequency temperature • supply voltage dependence | VCC = 4.75 to 5.25 V 0°C ≤ Topr ≤ 60°C ⁽²⁾ | 39.2 | 40 | 40.8 | MHz |
| | | VCC = 4.5 to 5.5 V -20°C ≤ Topr ≤ 85°C | 38.8 | 40 | 40.8 | MHz |
| | | VCC = 4.5 to 5.5 V -40°C ≤ Topr ≤ 85°C | 38.4 | 40 | 40.8 | MHz |
| | | VCC = 3.0 to 5.5 V -20°C ≤ Topr ≤ 85°C ⁽²⁾ | 38.8 | 40 | 41.2 | MHz |
| | | VCC = 3.0 to 5.5 V -40°C ≤ Topr ≤ 85°C ⁽²⁾ | 38.4 | 40 | 41.6 | MHz |
| | | VCC = 2.7 to 5.5 V -20°C ≤ Topr ≤ 85°C ⁽²⁾ | 38 | 40 | 42 | MHz |
| | | VCC = 2.7 to 5.5 V -40°C ≤ Topr ≤ 85°C ⁽²⁾ | 37.6 | 40 | 42.4 | MHz |
| | | VCC = 2.2 to 5.5 V -20°C ≤ Topr ≤ 85°C ⁽³⁾ | 35.2 | 40 | 44.8 | MHz |
| | | VCC = 2.2 to 5.5 V -40°C ≤ Topr ≤ 85°C ⁽³⁾ | 34 | 40 | 46 | MHz |
| | High-speed on-chip oscillator frequency when correction value in FRA7 register is written to FRA1 register ⁽⁴⁾ | VCC = 5.0 V, Topr = 25°C | — | 36.864 | — | MHz |
| | | VCC = 3.0 to 5.5 V -20°C ≤ Topr ≤ 85°C | -3% | — | 3% | % |
| — | Value in FRA1 register after reset | | 08h | — | F7h | — |
| — | Oscillation frequency adjustment unit of high-speed on-chip oscillator | Adjust FRA1 register (value after reset) to -1 | — | +0.3 | — | MHz |
| — | Oscillation stability time | | — | 10 | 100 | μs |
| — | Self power consumption at oscillation | VCC = 5.0 V, Topr = 25°C | — | 400 | — | μA |

NOTES:

1. VCC = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.
2. Standard values when the FRA1 register value after reset is assumed.
3. Standard values when the corrected value of the FRA6 register has been written to the FRA1 register.
4. This enables the setting errors of bit rates such as 9600 bps and 38400 bps to be 0% when the serial interface is used in UART mode.

Table 5.11 Low-speed On-Chip Oscillator Circuit Electrical Characteristics

| Symbol | Parameter | Condition | Standard | | | Unit |
|--------|--|--------------------------|----------|------|------|------|
| | | | Min. | Typ. | Max. | |
| fOCO-S | Low-speed on-chip oscillator frequency | | 30 | 125 | 250 | kHz |
| — | Oscillation stability time | | — | 10 | 100 | μs |
| — | Self power consumption at oscillation | VCC = 5.0 V, Topr = 25°C | — | 15 | — | μA |

NOTE:

1. VCC = 2.2 to 5.5 V, Topr = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.

Table 5.12 Power Supply Circuit Timing Characteristics

| Symbol | Parameter | Condition | Standard | | | Unit |
|---------|---|-----------|----------|------|------|------|
| | | | Min. | Typ. | Max. | |
| td(P-R) | Time for internal power supply stabilization during power-on ⁽²⁾ | | 1 | — | 2000 | μs |
| td(R-S) | STOP exit time ⁽³⁾ | | — | — | 150 | μs |

NOTES:

1. The measurement condition is VCC = 2.2 to 5.5 V and Topr = 25°C.
2. Waiting time until the internal power supply generation circuit stabilizes during power-on.
3. Time until system clock supply starts after the interrupt is acknowledged to exit stop mode.

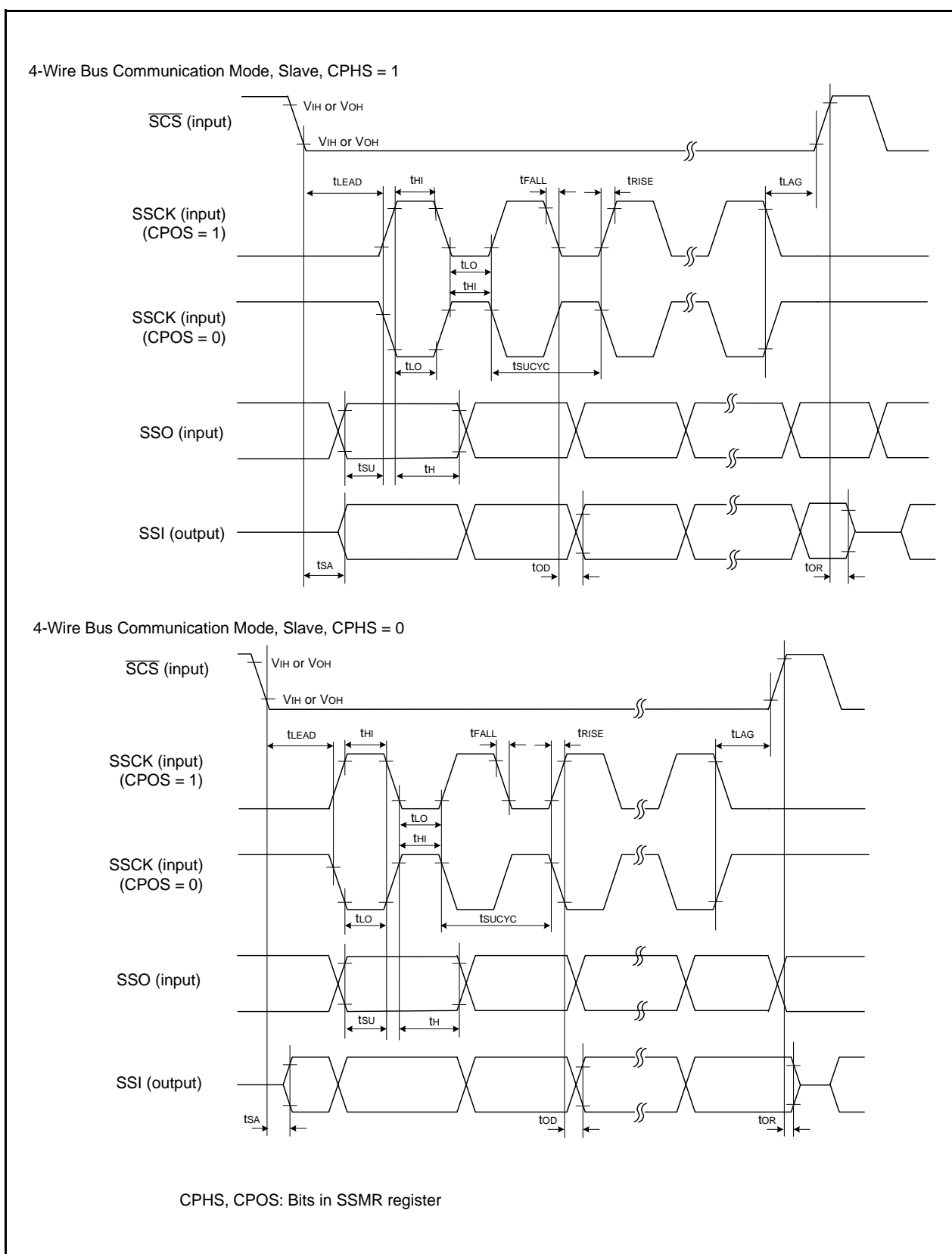


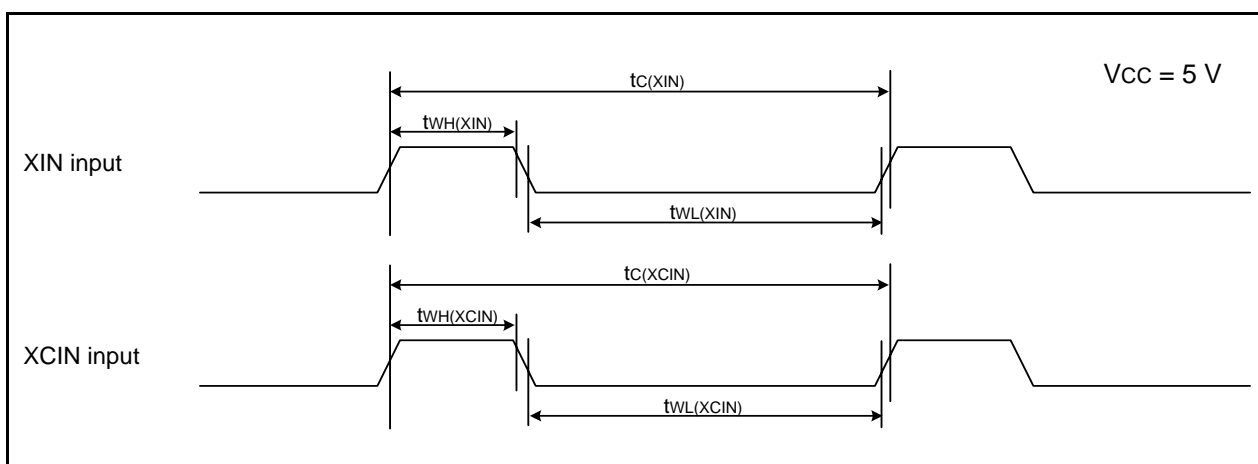
Figure 5.5 I/O Timing of Clock Synchronous Serial I/O with Chip Select (Slave)

Table 5.16 Electrical Characteristics (2) [V_{CC} = 5 V]
(T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

| Symbol | Parameter | Condition | | Standard | | | Unit |
|--------|---|--|--|----------|------|------|------|
| | | | | Min. | Typ. | Max. | |
| Icc | Power supply current (Vcc = 3.3 to 5.5 V) Single-chip mode, output pins are open, other pins are Vss | High-speed clock mode | XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division | – | 10 | 17 | mA |
| | | | XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division | – | 9 | 15 | mA |
| | | | XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz No division | – | 6 | – | mA |
| | | | XIN = 20 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8 | – | 5 | – | mA |
| | | | XIN = 16 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8 | – | 4 | – | mA |
| | | | XIN = 10 MHz (square wave) High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8 | – | 2.5 | – | mA |
| | | High-speed on-chip oscillator mode | XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz No division | – | 10 | 15 | mA |
| | | | XIN clock off High-speed on-chip oscillator on fOCO = 20 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8 | – | 4 | – | mA |
| | | | XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz No division | – | 5.5 | 10 | mA |
| | | | XIN clock off High-speed on-chip oscillator on fOCO = 10 MHz Low-speed on-chip oscillator on = 125 kHz Divide-by-8 | – | 2.5 | – | mA |
| | | Low-speed on-chip oscillator mode | XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator on = 125 kHz Divide-by-8, FMR47 = 1 | – | 130 | 300 | μA |
| | | Low-speed clock mode | XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz FMR47 = 1 | – | 130 | 300 | μA |
| | | | XIN clock off High-speed on-chip oscillator off Low-speed on-chip oscillator off XCIN clock oscillator on = 32 kHz Program operation on RAM Flash memory off, FMSTP = 1 | – | 30 | – | μA |

Timing Requirements(Unless Otherwise Specified: $V_{CC} = 5\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{op} = 25^{\circ}\text{C}$) [$V_{CC} = 5\text{ V}$]**Table 5.18 XIN Input, XCIN Input**

| Symbol | Parameter | Standard | | Unit |
|----------------|-----------------------|----------|------|---------------|
| | | Min. | Max. | |
| $t_{c(XIN)}$ | XIN input cycle time | 50 | – | ns |
| $t_{WH(XIN)}$ | XIN input "H" width | 25 | – | ns |
| $t_{WL(XIN)}$ | XIN input "L" width | 25 | – | ns |
| $t_{c(XCIN)}$ | XCIN input cycle time | 14 | – | μs |
| $t_{WH(XCIN)}$ | XCIN input "H" width | 7 | – | μs |
| $t_{WL(XCIN)}$ | XCIN input "L" width | 7 | – | μs |

**Figure 5.8 XIN Input and XCIN Input Timing Diagram when $V_{CC} = 5\text{ V}$** **Table 5.19 TRAIO Input**

| Symbol | Parameter | Standard | | Unit |
|-----------------|------------------------|----------|------|------|
| | | Min. | Max. | |
| $t_{c(TRAIO)}$ | TRAIO input cycle time | 100 | – | ns |
| $t_{WH(TRAIO)}$ | TRAIO input "H" width | 40 | – | ns |
| $t_{WL(TRAIO)}$ | TRAIO input "L" width | 40 | – | ns |

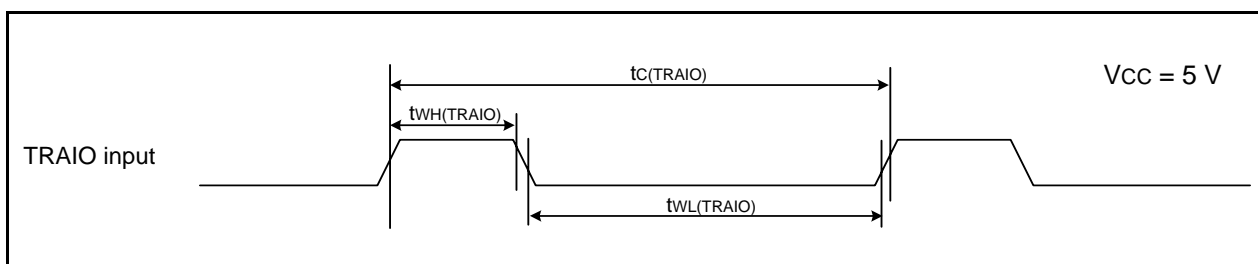
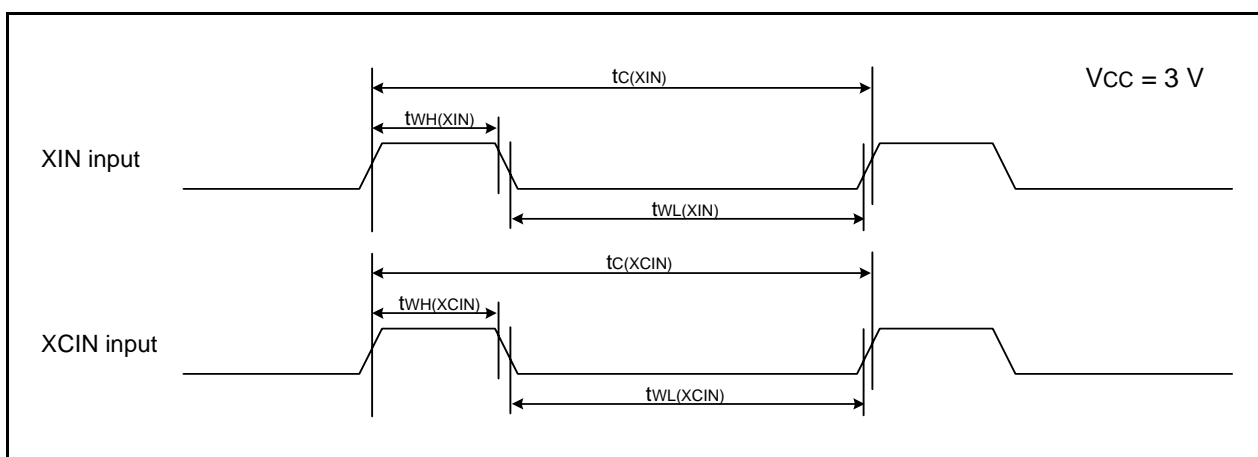
**Figure 5.9 TRAIO Input Timing Diagram when $V_{CC} = 5\text{ V}$**

Table 5.23 Electrical Characteristics (4) [Vcc = 3 V]
(T_{opr} = -20 to 85°C (N version) / -40 to 85°C (D version), unless otherwise specified.)

| Symbol | Parameter | Condition | Standard | | | Unit |
|-----------------|---|---|----------|------|------|------|
| | | | Min. | Typ. | Max. | |
| I _{cc} | Power supply current (V _{cc} = 2.7 to 3.3 V) Single-chip mode, output pins are open, other pins are V _{ss} | High-speed clock mode | – | 6 | – | mA |
| | | | | 2 | – | mA |
| | | High-speed on-chip oscillator mode | – | 5 | 9 | mA |
| | | | | 2 | – | mA |
| | | Low-speed on-chip oscillator mode | – | 130 | 300 | μA |
| | | | | 130 | 300 | μA |
| | | Wait mode | – | 25 | 70 | μA |
| | | | | 23 | 55 | μA |
| | | Increase during A/D converter operation | – | 0.9 | – | mA |
| | | | | 0.5 | – | mA |
| | | Stop mode | – | 0.7 | 3.0 | μA |
| | | | | 1.1 | – | μA |

Timing requirements**(Unless Otherwise Specified: $V_{CC} = 3\text{ V}$, $V_{SS} = 0\text{ V}$ at $T_{opr} = 25^{\circ}\text{C}$) [$V_{CC} = 3\text{ V}$]****Table 5.24 XIN Input, XCIN Input**

| Symbol | Parameter | Standard | | Unit |
|----------------|-----------------------|----------|------|---------------|
| | | Min. | Max. | |
| $t_{c(XIN)}$ | XIN input cycle time | 100 | – | ns |
| $t_{WH(XIN)}$ | XIN input "H" width | 40 | – | ns |
| $t_{WL(XIN)}$ | XIN input "L" width | 40 | – | ns |
| $t_{c(XCIN)}$ | XCIN input cycle time | 14 | – | μs |
| $t_{WH(XCIN)}$ | XCIN input "H" width | 7 | – | μs |
| $t_{WL(XCIN)}$ | XCIN input "L" width | 7 | – | μs |

**Figure 5.12 XIN Input and XCIN Input Timing Diagram when $V_{CC} = 3\text{ V}$** **Table 5.25 TRAIO Input**

| Symbol | Parameter | Standard | | Unit |
|-----------------|------------------------|----------|------|------|
| | | Min. | Max. | |
| $t_{c(TRAIO)}$ | TRAIO input cycle time | 300 | – | ns |
| $t_{WH(TRAIO)}$ | TRAIO input "H" width | 120 | – | ns |
| $t_{WL(TRAIO)}$ | TRAIO input "L" width | 120 | – | ns |

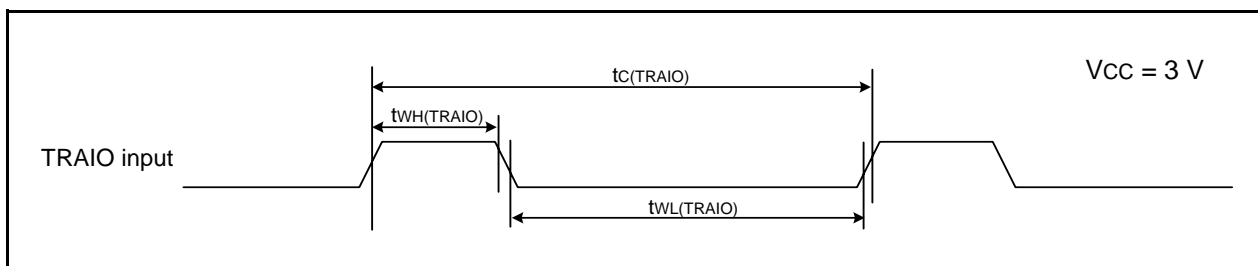
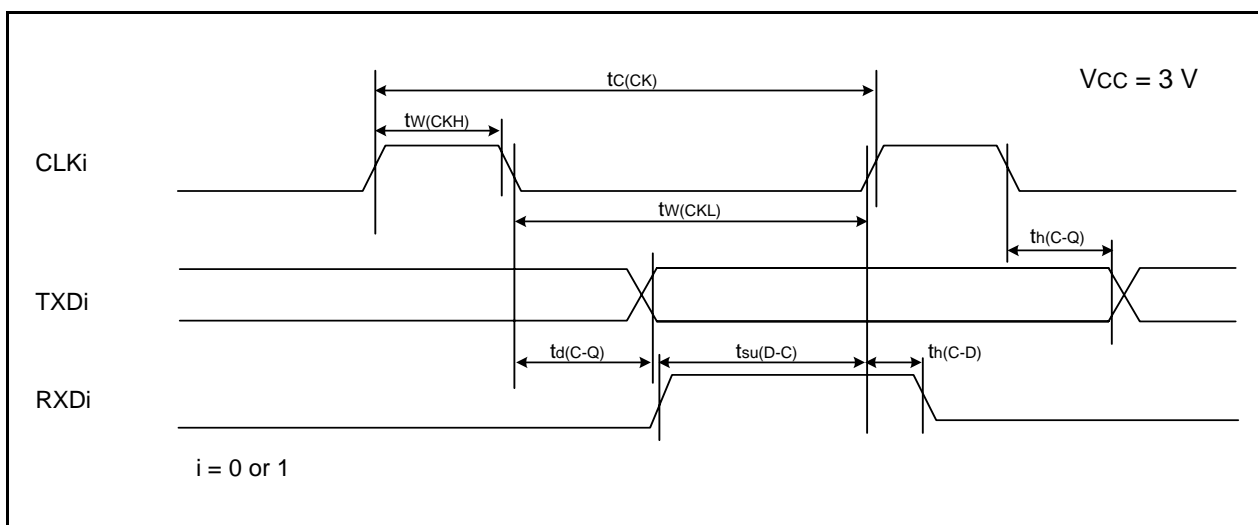
**Figure 5.13 TRAIO Input Timing Diagram when $V_{CC} = 3\text{ V}$**

Table 5.26 Serial Interface

| Symbol | Parameter | Standard | | Unit |
|---------------|------------------------|----------|------|------|
| | | Min. | Max. | |
| $t_{c(CK)}$ | CLKi input cycle time | 300 | — | ns |
| $t_{w(CKH)}$ | CLKi input "H" width | 150 | — | ns |
| $t_{w(CKL)}$ | CLKi Input "L" width | 150 | — | ns |
| $t_{d(C-Q)}$ | TXDi output delay time | — | 80 | ns |
| $t_{h(C-Q)}$ | TXDi hold time | 0 | — | ns |
| $t_{su(D-C)}$ | RXDi input setup time | 70 | — | ns |
| $t_{h(C-D)}$ | RXDi input hold time | 90 | — | ns |

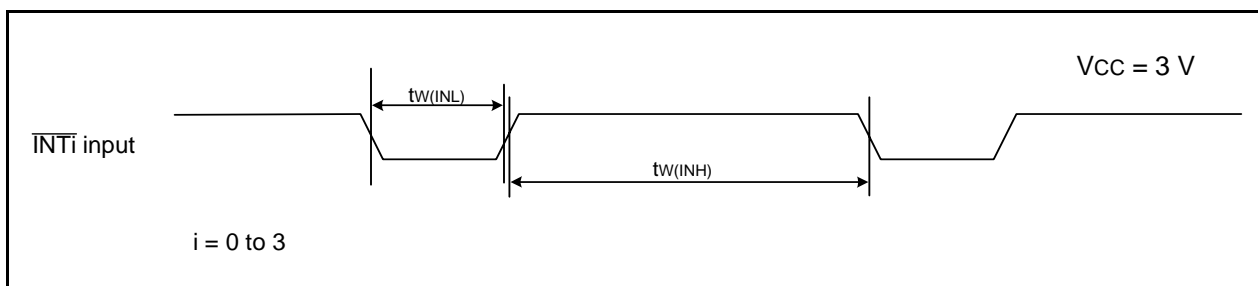
i = 0 or 1

**Figure 5.14 Serial Interface Timing Diagram when Vcc = 3 V****Table 5.27 External Interrupt \overline{INTi} (i = 0 to 3) Input**

| Symbol | Parameter | Standard | | Unit |
|--------------|-----------------------------------|--------------------|------|------|
| | | Min. | Max. | |
| $t_{w(INH)}$ | $\overline{INT0}$ input "H" width | 380 ⁽¹⁾ | — | ns |
| $t_{w(INL)}$ | $\overline{INT0}$ input "L" width | 380 ⁽²⁾ | — | ns |

NOTES:

- When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input HIGH width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.
- When selecting the digital filter by the \overline{INTi} input filter select bit, use an \overline{INTi} input LOW width of either (1/digital filter clock frequency × 3) or the minimum value of standard, whichever is greater.

**Figure 5.15 External Interrupt \overline{INTi} Input Timing Diagram when Vcc = 3 V**

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

| Rev. | Date | Description | |
|------|--------------|-------------|---|
| | | Page | Summary |
| 0.40 | Jan 24, 2006 | 15 | Table 4.1 SFR Information(1); 0024h: "TBD" → "When shipping" NOTES 3 and 4 revised |
| | | 19 | Table 4.5 SFR Information (5); 0118h: "Timer RE Second Data Register" → "Timer RE Second Data Register / Counter Data Register" 0119h: "Timer RE Minute Data Register" → "Timer RE Minute Data Register / Compare Data Register" 0138h: "TRDMDR" → "TRDMR" 013Bh: "Timer RD Output Master Enable Register" → "Timer RD Output Master Enable Register 1" |
| | | 22 | Table 5.1 Absolute Maximum Ratings; "VCC" → "VCC/AVCC" revised Table 5.2 Recommended Operating Conditions revised |
| | | 23 | Table 5.3 A/D Converter Characteristics revised |
| | | 24 | Table 5.4 Flash Memory (Program ROM) Electrical Characteristics revised |
| | | 25 | Table 5.5 Flash Memory (Data flash Block A, Block B) Electrical revised |
| | | 26 | Table 5.6 Voltage Detection 0 Circuit Electrical Characteristics revised Table 5.7 Voltage Detection 1 Circuit Electrical Characteristics revised Table 5.8 Voltage Detection 2 Circuit Electrical Characteristics revised |
| | | 28 | Table 5.11 High-speed On-Chip Oscillator Circuit Electrical Characteristics revised Table 5.12 Low-speed On-Chip Oscillator Circuit Electrical Characteristics revised Table 5.13 Power Supply Circuit Timing Characteristics revised |
| | | 29 | Table 5.14 Timing Requirements of Clock Synchronous Serial I/O with Chip Select revised |
| | | 33 | Table 5.15 Timing Requirements of I ² C bus Interface NOTE1 revised |
| | | 34 | Table 5.16 Electrical Characteristics (1) [VCC = 5 V] revised |
| | | 35 | Table 5.17 Electrical Characteristics (2) [VCC = 5 V] revised |
| | | 36 | Table 5.18 XIN Input, XCIN Input revised |
| | | 37 | Table 5.20 Serial Interface revised |
| | | 38 | Table 5.22 Electrical Characteristics (3) [VCC = 3 V] revised |
| | | 39 | Table 5.23 Electrical Characteristics (4) [Vcc = 3 V] revised |
| | | 40 | Table 5.24 XIN Input, XCIN Input revised |
| | | 41 | Table 5.26 Serial Interface revised |
| | | 42 | Table 5.28 Electrical Characteristics (5) [Vcc = 2.2 V] revised |
| | | 43 | Table 5.29 Electrical Characteristics (6) [Vcc = 2.2 V] revised |
| | | 44 | Table 5.30 XIN Input, XCIN Input revised Table 5.31 TRAIO Input, INT1 Input revised |
| | | 45 | Table 5.32 Serial Interface revised Table 5.33 External Interrupt INTi (i = 0, 2, 3) Input |

REVISION HISTORY

R8C/24 Group, R8C/25 Group Datasheet

| Rev. | Date | Description | |
|------|--------------|-------------|---|
| | | Page | Summary |
| 2.00 | Jul 14, 2006 | all pages | "PTLG0064JA-A (64F0G)" package added |
| | | 1 | 1. Overview; "... or a 64-pin molded-plastic FLGA." added |
| | | 2, 3 | Table 1.1 Functions and Specifications for R8C/24 Group, Table 1.2 Functions and Specifications for R8C/25 Group; Package: "64-pin molded-plastic FLGA" added |
| | | 5 | Table 1.3 Product Information for R8C/24 Group, Figure 1.2 Type Number, Memory Size, and Package of R8C/24 Group revised |
| | | 6 | Table 1.4 Product Information for R8C/25 Group, Figure 1.3 Type Number, Memory Size, and Package of R8C/25 Group revised |
| | | 7 | Figure 1.4 PLQP0052JA-A Package Pin Assignments (Top View); NOTE3 revised |
| | | 8 | Figure 1.5 PTLG0064JA-A Package Pin Assignments added |
| | | 14 | Figure 3.1 Memory Map of R8C/24 Group revised |
| | | 15 | Figure 3.2 Memory Map of R8C/25 Group revised |
| | | 23 | Table 5.1 Absolute Maximum Ratings; NOTE1 added |
| | | 47 | Package Dimensions; "PTLG0064JA-A (64F0G)" added |
| 3.00 | Feb 29, 2008 | all pages | Y version added |
| | | | Factory programming product added |
| | | 2, 3 | Table 1.1, Table 1.2 Clock; "Real-time clock (timer RE)" added |
| | | 5, 7 | Table 1.3, Table 1.4 revised |
| | | 6, 8 | Figure 1.2, Figure 1.3; ROM number "XXX" added |
| | | 16, 17 | Figure 3.1, Figure 3.2; "Expanded area" deleted |
| | | 18 | Table 4.1 revised |
| | | 26 | Table 5.2 NOTE2 revised |
| | | 32 | Table 5.10; revised, NOTE4 added |
| | | | Table 5.11; Oscillation stability time: Condition "Vcc = 5.0 V, Topr = 25°C" deleted |
| | | 38 | Table 5.15; I _{IH} , I _L , R _{PULLUP} Condition: "Vcc = 5V" added |
| | | 39 | Table 5.16; Condition: High-speed on-chip oscillator mode revised |
| | | 40 | Table 5.17 added |
| | | 41 | Figure 5.8 revised |
| | | 43 | Table 5.22; I _{IH} , I _L , R _{PULLUP} Condition: "Vcc = 3V" added |
| | | 44 | Table 5.23; Condition "Increase during A/D converter operation" added |
| | | 45 | Figure 5.12 revised |
| | | 48 | Table 5.29; Condition "Increase during A/D converter operation" added |
| | | 49 | Figure 5.16 revised |
| | | | |